

NB3V1106CDTR2G Datasheet

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DiGi Electronics Part Number	NB3V1106CDTR2G-DG
Manufacturer	onsemi
Manufacturer Product Number	NB3V1106CDTR2G
Description	IC CLK BUFFER 1:6 250MHZ 14TSSOP
Detailed Description	Clock Fanout Buffer (Distribution) IC 1:6 250 MHz 14 -TSSOP (0.173", 4.40mm Width)

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
NB3V1106CDTR2G	onsemi
Series:	Product Status:
-3.02	Active
Туре:	Number of Circuits:
Fanout Buffer (Distribution)	1
Ratio - Input:Output:	Differential - Input:Output:
1:6	No/No
Input:	Output:
LVCMOS	LVCMOS
Frequency - Max:	Voltage - Supply:
250 MHz	1.71V ~ 3.6V
Operating Temperature:	Mounting Type:
-40°C ~ 105°C	Surface Mount
Package / Case:	Supplier Device Package:
14-TSSOP (0.173", 4.40mm Width)	14-TSSOP
Base Product Number:	
NB3V1106	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8542.39.0001	

onsemi

3.3 V / 2.5 V / 1.8 V LVCMOS Low Skew Fanout Buffer Family



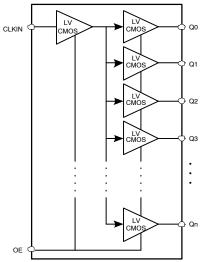
Description

The NB3V110xC are a modular, high-performance, low-skew, general purpose LVCMOS clock buffer family. The family of devices is designed with a modular approach. Four different fan-out variations, 1:2, 1:3, 1:4, 1:6 and 1:8, are available. All of the devices are pin compatible to each other for easy handling. All family members share the same high performing characteristics like low additive jitter, low skew, and wide operating temperature range. The NB3V110xC supports an asynchronous output enable control (OE) which switches the outputs into a low state when OE is low. The NB3V110xC devices operate in a 3.3 V, 2.5 V and 1.8 V environment and are characterized for operation from -40° C to 105° C.

Features

- Operating Temperature Range: -40°C to 105°C
- High-Performance 1:2, 1:3, 1:4, 1:6, 1:8 LVCMOS Clock Buffer
- Available in 8–, 14–, 16–Pin TSSOP and WDFN8 Packages
- Very Low Output–to–Output Skew < 50 ps
- Very Low Additive Jitter < 200 fs
- Supply Voltage: 3.3 V, 2.5 V or 1.8 V
- f_{max} = 250 MHz for 3.3 V; f_{max} = 180 MHz for 2.5 V; f_{max} = 133 MHz for 1.8 V
- These Devices are Pb-Free and are RoHS Compliant

BLOCK DIAGRAM







TSSOP-8 DT SUFFIX CASE 948S

TSSOP-16 DT SUFFIX CASE 948F

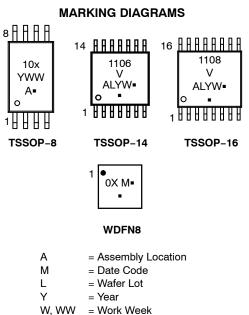


TSSOP-14

DT SUFFIX

CASE 948G

WDFN8, 2x2 MT SUFFIX CASE 511AT

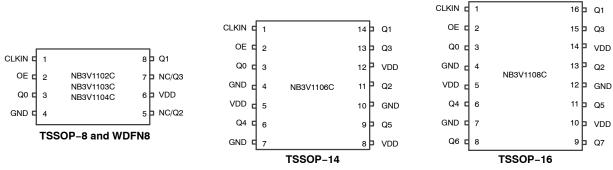


= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 9 of this data sheet.



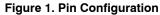


Table 1. PIN DESCRIPTION

	LVCMOS Clock Input	LVCMOS Clock Output Enable	LVCMOS Clock Output	Device Supply Voltage	Device Ground
Devices	CLKIN	OE	Q0, Q1, Q7	VDD	GND
NB3V1102C	1	2	3, 8	6	4
NB3V1103C	1	2	3, 8, 5	6	4
NB3V1104C	1	2	3, 8, 5, 7	6	4
NB3V1106C	1	2	3, 14, 11, 13, 6, 9	5, 8, 12	4, 7, 10
NB3V1108C	1	2	3, 16, 13, 15, 6, 11, 8, 9	5, 10, 14	4, 7, 12

NOTE: Pins not mentioned in the table are NC.

Table 2. OUTPUT LOGIC TABLE

INP	OUTPUTS	
CLKIN	OE	Qn
Х	L	L
L	Н	L
Н	Н	Н

Table 3. ATTRIBUTES

	Characteristic	Value	Unit
ESD Protection	Human Body Model (HBM) per ANSI/ESDA/JEDEC JS-001-2014 Charged Device Model (CDM) per ANSI/ESDA/JEDEC JS-002-2014		V V
Moisture Sensitivity, Ir	Moisture Sensitivity, Indefinite Time Out of Dry Pack (Note 1)		-
Meets or exceeds JEE	DEC Spec JESD78D (LU) IC Latchup Test		

1. JEDEC standard multilayer board - 2S2P (2 signal, 2 power) with a large copper heat spreader (20 mm², 2 oz.)

Table 4. ABSOLUTE MAXIMUM RATINGS (Note 2) Over operating free-air temperature range (unless otherwise noted)

Symbol	Condition	Value	Unit	
V_{DD}	Supply Voltage Range	–0.5 to 4.6	V	
V _{IN}	Input Voltage Range (Note 3)		–0.5 to V _{DD} + 0.5	V
Vo	Output Voltage Range (Note 3)		–0.5 to V _{DD} + 0.5	V
I _{IN}	Input Current		±20	mA
Ι _Ο	Continuous Output Current		±50	mA
θ_{JA}	A Thermal Resistance (Junction-to-Ambient) TSSOP-8		151.2*	°C/W
		TSSOP-14	104*	
		T000D 40	32*	
		TSSOP-16	110**	
		WDFN8	190**	
θJC	Thermal Resistance (Junction-to-Case top)	TSSOP-8	35	°C/W
		TSSOP-14	8.6	
		TSSOP-16	10	
		WDFN8	10	1
TJ	Maximum Junction Temperature		125	°C
T _{STG}	Storage Temperature Range		-65 to 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
2. JEDEC standard multilayer board – 2S2P (2 signal, 2 power) with a large copper heat spreader (20 mm², 2 oz.)
3. For additional information, see Application Note AND8003/D.
*JEDEC51.7 four layer PCB with 100 sqmm, 2 oz with two 80x80x1oz ground planes.

**JEDEC51.3 two layer PCB with 100 sqmm, 2 oz.

Table 5. RECOMMENDED OPERATING CONDITIONS

Over operating free-air temperature range (unless otherwise noted)

Symbol	Conditio	on	Min	Тур	Max	Unit
V_{DD}	Supply voltage range	3.3 V supply	3.0	3.3	3.6	V
		2.5 V supply	2.3	2.5	2.7	
		1.8 V supply	1.71	1.8	1.89	
V _{IL}	Low-level input voltage	V_{DD} = 3.0 V to 3.6 V			$V_{DD}/2 - 600$	mV
		V_{DD} = 2.3 V to 2.7 V			$\frac{V_{\text{DD}}/2}{400} -$	
		V _{DD} = 1.71 V to 1.89 V			$0.3 \mathrm{xV}_{\mathrm{DD}}$	V
V _{IH}	High-level input voltage	V _{DD} = 3.0 V to 3.6 V	V _{DD} /2 + 600			mV
		V_{DD} = 2.3 V to 2.7 V	V _{DD} /2 + 400			
		V _{DD} = 1.71 V to 1.89 V	$0.7 \mathrm{xV}_{\mathrm{DD}}$			V
V_{th}	Input threshold voltage	V _{DD} = 2.3 V to 3.6 V		$V_{DD}/2$		V
		V _{DD} = 1.71 V to 1.89 V		$V_{DD}/2$		V
t _r / t _f	Input slew rate (Note 4)		1		4	V/n
t _w	Minimum pulse width at CLKIN	V _{DD} = 3.0 V to 3.6 V	1.8			ns
		V _{DD} = 2.3 V to 2.7 V	2.75			
		V _{DD} = 1.71 V to 1.89 V	3.75			
fclk	LVCMOS clock Input Frequency	V _{DD} = 3.0 V to 3.6 V	DC		250	MH
		V _{DD} = 2.3 V to 2.7 V	DC		180	
		V _{DD} = 1.71 V to 1.89 V	DC		133	
T _A	Operating free-air temperature	•	-40		105	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

4. Guaranteed by Design.

Table 6. DEVICE CHARACTERISTICS Over recommended operating free-air temperature range (unless otherwise noted) (I

Symbol	Parameter	Condition	Min	Тур	Max	Unit
OVERALL F	ARAMETERS FOR ALL VERSIONS					
I _{DD}	Static device current	OE = V _{DD} ; CLKIN = 0 V or V _{DD} ; I _O = 0 mA; V _{DD} = 3.6 V			0.2	mA
		OE = V _{DD} ; CLKIN = 0 V or V _{DD} ; I _O = 0 mA; V _{DD} = 2.7 V			0.2	
		OE = V _{DD} ; CLKIN = 0 V or V _{DD} ; I _O = 0 mA; V _{DD} = 1.89 V			0.2	
I _{PD}	Power down current	OE = 0 V; CLKIN = 0 V or V_{DD} ; I_0 = 0 mA; V_{DD} = 3.6 V, 2.7 V or 1.89 V (For 1102C, 1103C, 1104C)			60 µ	μΑ
		OE = 0 V; CLKIN = 0 V or V_{DD} ; I_0 = 0 mA; V_{DD} = 3.6 V, 2.7 V or 1.89 V (For 1106C, 1108C)			75	
C _{PD}	Power dissipation capacitance per out-	V _{DD} = 3.3 V; f = 10 MHz		9		pF
	put (Note 6)	V _{DD} = 2.5 V; f = 10 MHz		9		1
		V _{DD} = 1.8 V; f = 10 MHz		9		1
I _I	Input leakage current at OE	lge current at OE $V_1 = 0 V \text{ or } V_{DD}, V_{DD} = 3.6 V \text{ or } 2.7 V$			± 8	μA
	Input leakage current at CLKIN				± 8	1
	Input leakage current at OE, CLKIN	V _I = 0 V or V _{DD} , V _{DD} = 1.89 V			± 8	1
R _{OUT}	Output impedance	V _{DD} = 3.3 V		40		Ω
		V _{DD} = 2.5 V		45		1
		V _{DD} = 1.8 V		60		1
fout	Output frequency	V _{DD} = 3.0 V to 3.6 V	DC		250	MHz
		V _{DD} = 2.3 V to 2.7 V	DC		180	
		V _{DD} = 1.71 V to 1.89 V	DC		133	
UTPUT PA	RAMETERS FOR V_{DD} = 3.3 V ± 0.3 V					
V _{OH}	High-level output voltage	V _{DD} = 3 V, I _{OH} = -0.1 mA	2.9			V
		V _{DD} = 3 V, I _{OH} = -8 mA	2.5			1
		V _{DD} = 3 V, I _{OH} = -12 mA	2.2			1
V _{OL}	Low-level output voltage	V _{DD} = 3 V, I _{OL} = 0.1 mA			0.1	V
		V _{DD} = 3 V, I _{OL} = 8 mA			0.5	1
		V _{DD} = 3 V, I _{OL} = 12 mA			0.8	1
t _{PLH} , t _{PHL}	Propagation delay (Note 7)	CLKIN to Qn	0.8		2.0	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

12 kHz...20 MHz f_{OUT} = 100 MHz

12 kHz...20 MHz f_{OUT} = 156.25 MHz

Equal load of each output 85°C

Equal load of each output 105°C

To be measured with input duty cycle of 50%

Under equal operating conditions for two parts

20%–80% (V_{OH} – V_{OL})

OE to Qn

OE to Qn

50

60

0.8

6

6

180

0.5

100

0.12

ps

ns

ns

ns

ps

ns

fs

5. All typical values are at respective nominal V_{DD}. For switching characteristics, outputs are terminated to 50 Ω to V_{DD}/2 (see Figure 2).

All typical values are at respective horninal V_{DD}. For swifted the formula for the power dissipation calculation. Ptot = Pstat + Pdyn + PCload [W] P_{stat} = V_{DD} x I_{DD} [W] P_{dyn} = C_{PD} x V_{DD}2 x f x n [W] P_{Cload} = C_{load} x V_{DD}2 x f x n [W] n = Number of switching output pins
With under sell and shock.

Output skew (Note 7)

Output disable time (Note 7)

Output enable time (Note 7)

Pulse skew; tPLH(Qn) - tPHL(Qn) (Note 8)

Rise and fall time

Part-to-part skew

Additive jitter rms

t_{sk(o)}

t_r/t_f

t_{DIS} t_{EN}

t_{sk(p)}

t_{sk(pp)}

Τ_{jit(φ)}

7. With rail to rail input clock.

^{8.} $t_{sk(p)}$ depends on output rise- and fall-time (t_r/t_f). The output duty-cycle can be calculated: odc = ($t_{w(OUT)} \pm t_{sk(p)}$)/ t_{period} ; $t_{w(OUT)}$ is pulse-width of ideal output waveform and tperiod is 1/f_{OUT}.

Table 7. DEVICE CHARACTERISTICS (continued)

Over recommended operating free-air temperature range (unless otherwise noted) (Note 5)

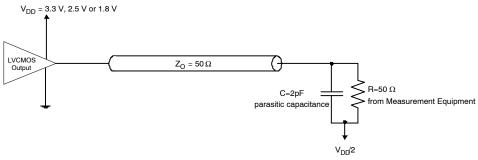
Symbol	Parameter	Condition	Min	Тур	Max	Unit
	RAMETERS FOR $V_{DD} = 2.5 V \pm 0.100$	2 V				
V _{OH}	High-level output voltage	V _{DD} = 2.3 V, I _{OH} = -0.1 mA	2.2			V
		V _{DD} = 2.3 V, I _{OH} = -8 mA	1.7			
V _{OL}	Low-level output voltage	V _{DD} = 2.3 V, I _{OL} = 0.1 mA			0.1	V
		V _{DD} = 2.3 V, I _{OL} = 8 mA			0.5	
t _{PLH} , t _{PHL}	Propagation delay (Note 10)	CLKIN to Qn		1.8		ns
t _{sk(o)}	Output skew (Note 10)	Equal load of each output 85°C			50	ps
		Equal load of each output 105°C			60	1
t _r /t _f	Rise and fall time	20%–80% (V _{OH} – V _{OL})	0.12		1.2	ns
t _{DIS}	Output disable time (Note 10)	OE to Qn			10	ns
t _{EN}	Output enable time (Note 10)	OE to Qn			10	ns
t _{sk(p)}	$\begin{array}{l} \mbox{Pulse skew ; }^{t}\mbox{PLH}(\mbox{Qn}) - t\mbox{PHL}(\mbox{Qn}) \\ \mbox{(Note 9)} \end{array}$	To be measured with input duty cycle of 50%			220	ps
t _{sk(pp)}	Part-to-part skew	Under equal operating conditions for two parts			1.2	ns
tjit _(φ)	Additive jitter rms	12 kHz20 MHz f _{OUT} = 100 MHz			150	fs
		12 kHz20 MHz f _{OUT} = 156.25 MHz			100	
	RAMETERS FOR V _{DD} = 1.8 V ± 59	%		•	-	-
VOH	High-level output voltage	V _{DD} = 1.71 V, I _{OH} = -0.1 mA	1.6			V

V _{OH}	High-level output voltage	V _{DD} = 1.71 V, I _{OH} = -0.1 mA	1.6		V
		V _{DD} = 1.71 V, I _{OH} = -4 mA	0.75xV _{DD}		
V _{OL}	Low-level output voltage	V _{DD} = 1.71 V, I _{OL} = 0.1 mA		0.1	V
		V _{DD} = 1.71 V, I _{OL} = 4 mA		$0.25 \mathrm{xV}_{\mathrm{DD}}$	
t _{PLH} , t _{PHL}	Propagation delay (Note 10)	CLKIN to Qn	1.8	3.5	ns
t _{sk(o)}	Output skew (Note 10)	Equal load of each output		75	ps
t _r /t _f	Rise and fall time	20%–80% (V _{OH} – V _{OL})	0.17	1.2	ns
t _{DIS}	Output disable time (Note 10)	OE to Qn		10	ns
t _{EN}	Output enable time (Note 10)	OE to Qn		10	ns
t _{sk(p)}	Pulse skew ; ^t PLH(Qn) - tPHL(Qn) (Note 9)	To be measured with input duty cycle of 50%		450	ps
t _{sk(pp)}	Part-to-part skew	Under equal operating conditions for two parts		1.2	ns
tjit _(φ)	Additive jitter rms	12 kHz20 MHz, f _{OUT} = 100 MHz		200	fs

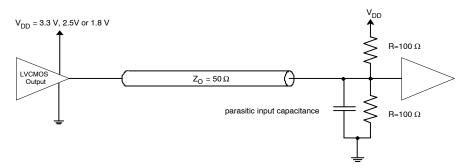
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 9. $t_{sk(p)}$ depends on output rise- and fall-time (t_r/t_f). The output duty-cycle can be calculated: odc = ($t_{w(OUT)} \pm t_{sk(p)}$)/ t_{period} ; $t_{w(OUT)}$ is

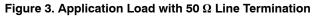
pulse-width of ideal output waveform and tperiod is 1/f_{OUT}. 10. With rail to rail input clock.

PARAMETERS MEASUREMENT INFORMATION









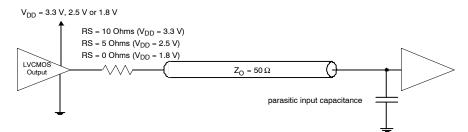


Figure 4. Application Load with Series Line Termination

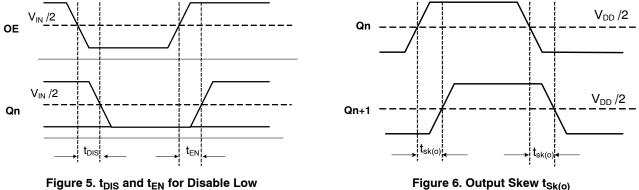
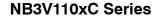
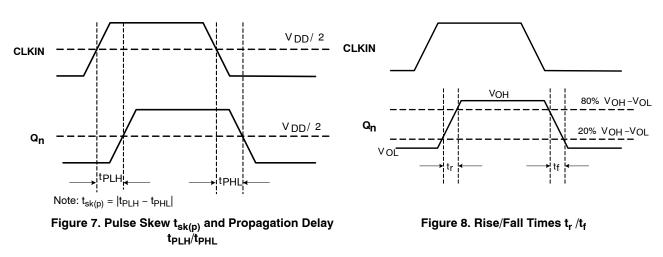
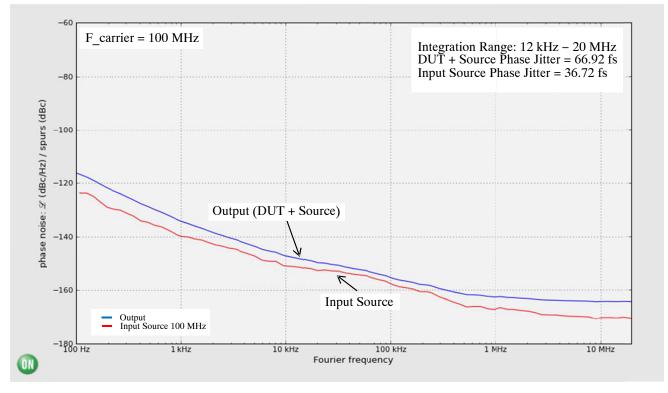
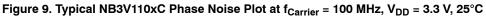


Figure 6. Output Skew t_{Sk(o)}









The above phase noise data was captured using Agilent E5052A/B. The data displays the input phase noise and output phase noise used to calculate the additive phase jitter at a specified integration range. The additive RMS phase jitter contributed by the device (integrated between 12 kHz and 20 MHz) is 55.94 fs. The additive RMS phase jitter performance of the fan out buffer is highly dependent on the phase noise of the input source.

To obtain the most precise additive phase noise measurement, it is vital that the source phase noise be notably lower than that of the DUT. If the phase noise of the source is greater than the noise floor of the device under test, the source noise will dominate the additive phase jitter calculation and lead to an incorrect negative result for the additive phase noise within the integration range. The Figure above is a good example of the NB3V110xC source generator phase noise having a significantly lower floor than the DUT and results in an additive phase jitter of 55.94 fs.

Additive RMS phase jitter = $\sqrt{\text{RMS}}$ phase jitter of output² – RMS phase jitter of input²

55.94 fs = $\sqrt{66.92 \text{ fs}^2 - 36.72 \text{ fs}^2}$

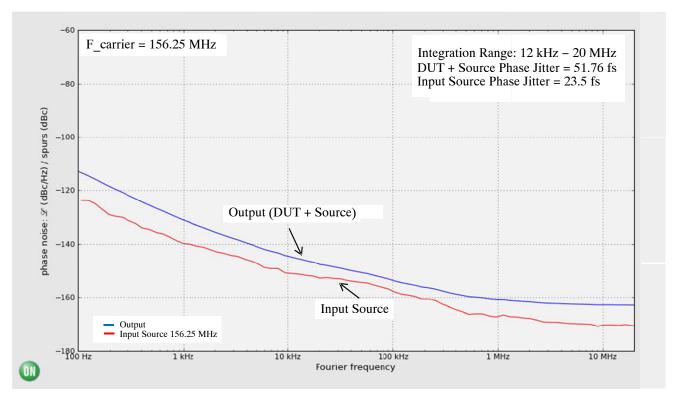


Figure 10. Typical NB3V110xC Phase Noise Plot at f_{Carrier} = 156.25 MHz, V_{CC} = 3.3 V V, 25°C

The additive RMS phase jitter contributed by the device (integrated between 12 kHz and 20 MHz) is 46.11 fs.

Additive RMS phase jitter = $\sqrt{\text{RMS phase jitter of output}^2 - \text{RMS phase jitter of input}^2}$

46.11 fs =
$$\sqrt{51.76 \text{ fs}^2 - 23.5 \text{ fs}^2}$$

Figures 9 and 10 were created with measured data from Agilent–E5052A/B Signal Source Analyzer using **onsemi** Phase Noise Explorer web tool. This free application enables an interactive environment for advanced phase noise and jitter analysis of timing devices and clock tree designs. To see the performance of NB3V110xC beyond conditions outlined in this datasheet, please visit the **onsemi** Green Point Design Tools homepage.

Device	Marking	Package	Shipping [†]
NB3V1102CDTR2G	102		
NB3V1103CDTR2G	103	TSSOP-8 (Pb-Free)	2500 / Tape & Reel
NB3V1104CDTR2G	104		
NB3V1102CMTTBG	02	WDFN8	
NB3V1104CMTTBG	04	(Pb-Free) 3000 / Tape & Re	
NB3V1106CDTR2G	1106 V	TSSOP-14 (Pb-Free)	2500 / Tape & Reel
NB3V1108CDTR2G	1108 V	TSSOP-16 (Pb-Free)	2500 / Tape & Reel

Table 8. ORDERING INFORMATION

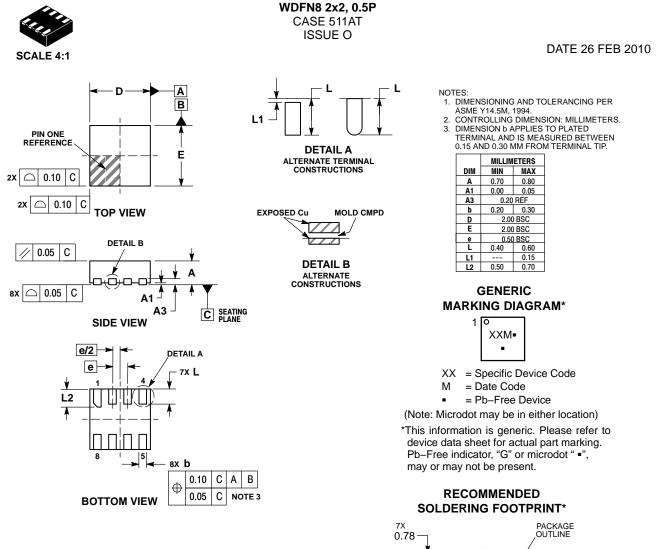
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

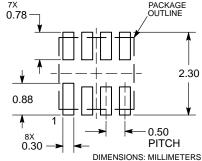
NOTE: Please contact your onsemi sales representative for availability of parts in tube.



MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS





*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

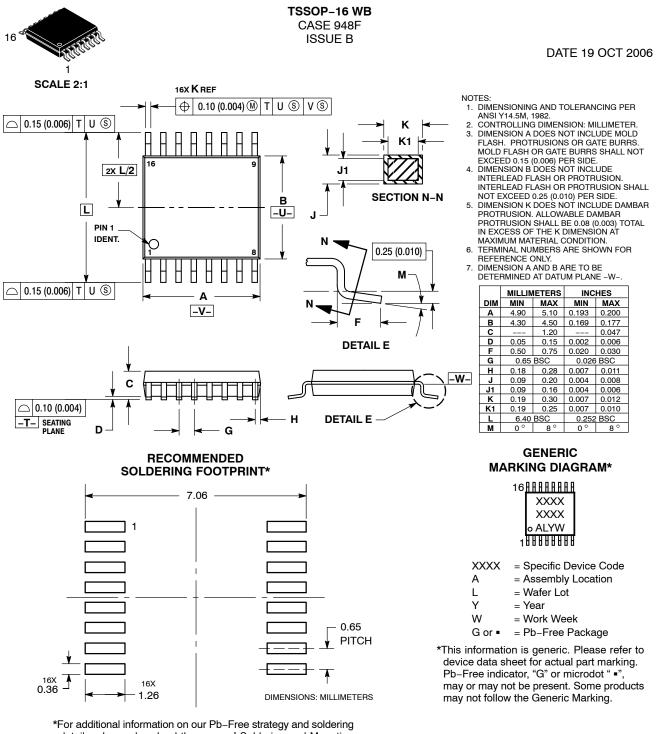
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MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



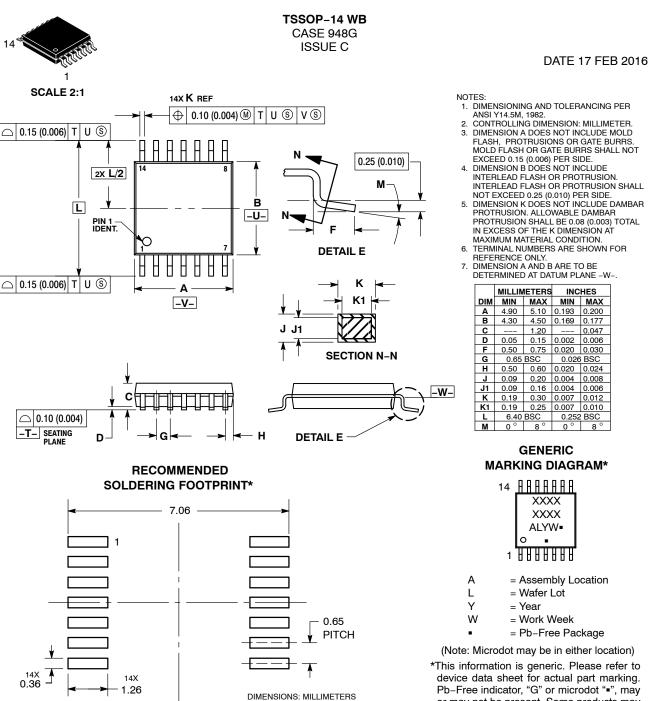
details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

or may not be present. Some products may not follow the Generic Marking.

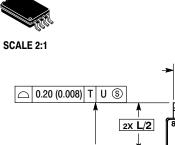
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MECHANICAL CASE OUTLINE

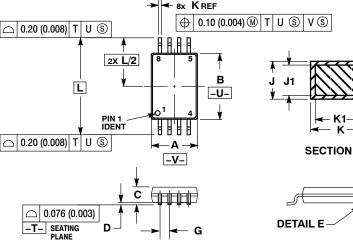
PACKAGE DIMENSIONS



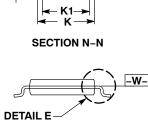
D

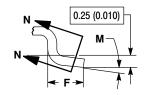
TSSOP-8 3.0x4.4x1.1 CASE 948S ISSUE C

DATE 20 JUN 2008



G





DETAIL E

NOTES:

- IOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER. 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15
- (0.006) PER SIDE. 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010)
- PER SIDE. 5. TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-. 6.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	2.90	3.10	0.114	0.122	
В	4.30	4.50	0.169	0.177	
С		1.10		0.043	
D	0.05	0.15	0.002	0.006	
F	0.50	0.70	0.020	0.028	
G	0.65	0.65 BSC		0.026 BSC	
J	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
K	0.19	0.30	0.007	0.012	
K1	0.19	0.25	0.007	0.010	
L	6.40 BSC		0.252 BSC		
М	0°	8°	0°	8°	

GENERIC **MARKING DIAGRAM***

0	XXX
	YWW
	A•
	-

XXX	= Specific Device Code
Α	= Assembly Location
Y	= Year
WW	= Work Week
	= Pb-Free Package

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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